

MB85R256FPF-G-BND-ERE1

MB85R256FPF-G-BND-ERE1 Information

Con Heisener.com	 MB85R256FPF-G-BND-ERE1 Fujitsu Electronics America, Inc. Integrated Circuits (ICs) Memory IC FRAM 256KBIT PAR 28SOP - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MB85R256FPF-G-BND-ERE1 Specifications

Manufacturer Part Number	MB85R256FPF-G-BND-ERE1
Manufacturer	Fujitsu Electronics America, Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	FRAM
Technology	FRAM (Ferroelectric RAM)
Memory Size	256Kb (32K x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	150ns
Access Time	150ns
Voltage - Supply	2.7 V ~ 3.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

MB85R256FPF-G-BND-ERE1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MB85R256FPF-G-BND-EREI Payment Methods WIRE Transfer PayPal Pay

If you have any question about MB85R256FPF-G-BND-ERE1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com